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41 GHz and 10.6 GHz low threshold and low noise InAs/InP quantum dash two-section mode-locked lasers in L band


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This paper reports recent results on InAs/InP quantum dash–based, two-section, passively mode-locked lasers pulsing at 41 GHz and 10.6 GHz and emitting at 1.59 µm at 20 °C. The 41-GHz device (1 mm long) starts lasing at 25 mA under uniform injection and the 10.6 GHz (4 mm long) at 71 mA. Their output pulses are significantly chirped. The 41-GHz laser exhibits 7 ps pulses after propagation in 60 m of a single-mode fiber. The 10.6-GHz laser generates one picosecond pulses with 545 m of a single-mode fiber. Its single side-band phase noise does not exceed –80 dBc/Hz at 100 kHz offset, leading to an average timing jitter of 800 fs. © 2012 American Institute of Physics. [doi:10.1063/1.3677976]

I. INTRODUCTION

Monolithic mode-locked diode lasers are highly interesting for ultra high bit rate optical telecommunication systems, because they can generate pulse trains of several GHz. These lasers have long been fabricated with quantum wells, but with quantum dots, they have shown better performances in terms of pulse duration, noise performance, and peak power. Mode-locking with InAs quantum dots on a GaAs substrate has indeed been demonstrated with frequencies ranging from 191 MHz (Ref. 2) to 200 GHz, pulse durations from tens of picoseconds to 400 fs, and with low noise and peak powers up to 15 W. Short pulses with low noise and high peak power are important in order to achieve low error-bit rate communications.

InAs/GaAs quantum dot laser emission wavelength is normally situated in the 1-1.3 µm range and has been demonstrated to reach 1.46 µm, though with high threshold current. Much attention is now devoted to the InAs/InP material system in order to reach the 1.55-µm wavelength emission required for the standards of long-haul telecommunications. This system provides quantum dots and also quantum dashes, depending on the growth procedure and the substrate orientation. The use of quantum dashes should also provide improvements over quantum wells, but at a lesser extent than quantum dots.

Achievements of passive mode-locking using InAs/InP quantum nanostructures leading to high pulse repetition rate up to 346 GHz (Ref. 9) and Fourier-limited short pulses down to 312 fs (Ref. 10) have been reported on single-section lasers. Heck et al. recently reported passive mode–locking in two-section InAs/InP quantum dot lasers up to 10.5 GHz between 600 mA and 750 mA injection current at 10 °C.

While the best performances have been demonstrated using single-section lasers, multi-section lasers having at least one section used as a saturable absorber (SA) are normally preferred for stable operation. Through the device absorber to gain lengths ratio defined during mask processing and the reverse bias voltage applied to the SA, the mode-locking can be altered to meet a specific requirement. Moreover, the mode-locked signal could be synchronized with an external reference clock, electrically modulating the absorber with the same period as the cavity round-trip time. Depending on the clock stability, this could lead to a decreased jitter.

In this paper, we report the fabrication and characterization of low threshold, passively mode-locked 4-mm and 1-mm-long two-section quantum dash lasers with short pulses and low noise.

II. FABRICATION OF THE LASERS AND STATIC CHARACTERIZATION

The investigated semiconductor structure was grown by gas source molecular beam epitaxy (GSMBE) on InP (100) substrate. The active material consists of 5 layers of InAs quantum dashes grown using the double cap method. The latter consists of growing the capping layer over the dashes in two steps separated by a growth interruption under phosphorus flux to reduce the height of the highest dashes. As a result, the carrier lifetime is increased from about 700 ps (Ref. 14) to 1600 ps (Ref. 15), leading to lower threshold current lasers. Indeed, this method should allow stacking of several layers with fewer defects. The capping layers consist of 20-nm-thick phosphide quaternary emitting at 1.18 µm (PQ(1.18)) layers (Ga0.20In0.80As0.433P0.565). The stack is centered in a 320-nm-thick waveguide of PQ(1.18) cladded by InP layers (Fig. 1).

The fabricated devices are edge-emitting Fabry Perot multi-section ridge lasers. The ridge width is 2 µm, and the etching was done until about 100 nm of p-type InP is left above the waveguide. The electrical isolation between the sections was done by etching through the highly doped...
contact layers in a 5-μm trench on top of the ridge. The length of the SA section is about 3 to 4% the total length of the laser, and the facet on its end is coated with silver for high reflectivity (Fig. 2). The SA section length ratio was chosen on the basis of a low signal absorption value of the quantum dashes. Lasers with higher ratio indeed exhibited lower output power. The low signal absorption was later measured and showed a value as high as 50 cm⁻¹.

For characterization, the device was placed on a copper block maintained at 20°C by means of a thermo-electric cooler. The output of the laser was coupled to a single-mode fiber (SMF) through an antireflection-coated, lensed isolator and distributed to 4 outputs for the power meter, the optical spectrum analyzer (10 pm resolution), the RF spectrum analyzer (22 GHz bandwidth), and the autocorrelator. An L-band amplifier was used for the autocorrelation measurement.

Measurements of light-current characteristics showed a threshold current of 71 mA for the 4-mm laser and 25 mA for the 1-mm one under uniform injection (Fig. 3). For all the measurements presented in this paper, the gain current was set so as to achieve a high fiber-coupled output power of 7 to 8 mW (Fig. 3).

III. PASSIVE MODE-LOCKING: RESULTS AND DISCUSSION

In this section, we report results of passive mode-locking achieved with the devices. In order to obtain mode-locking, the SA was reverse biased. This bias voltage was set so as the RF peak reached its highest value. As a consequence and according to the fiber-coupled output power requirement (Fig. 3), the operating conditions applied for all the measurements presented here are a gain current of 250 mA with an absorber bias voltage of −1.6 V for the 4-mm laser and 140 mA with −2.7 V, respectively, for the 1-mm laser.

For the 4-mm laser, under uniform current injection, the optical spectrum measurement showed a peak at 1595 nm with a width of 6.7 nm. When the reverse bias was on, the linewidth increased to 7.2 nm. In the latter case, the appearance of smooth bumps on part of the optical spectrum (Fig. 4) and a strong increase in the RF peak indicate that partial mode-locking is happening. However, no pulse could be seen in the double background–free autocorrelation or on a fast oscilloscope, indicating that the total output power from the laser was not pulsing in a normal sense.

To further investigate the laser signal, a 1-nm bandwidth filter centered at 1600 nm and tuneable on a window of 20 nm was used. This way, autocorrelations led to the measurements of pulses ranging from 9 to 16 ps, depending on the part of the laser spectrum selected by the filter. The shortest pulses measured were corresponding to the extreme left and right parts of the spectrum, as seen in Fig. 5.

The result seems to match with the characteristics of strongly linear-chirped pulses. Indeed, on a linear-chirped radiation, a spectral filter is equivalent to a window in the time domain. Thus, the measured pulse width is directly related to the size of the overlapping region between the pulse and the temporal window. Selecting the edges of the mode-locked spectrum only lets the edges of the pulses pass, which yields short pulse measurements. Selecting the center yields the longest pulses.

To investigate the assumption of chirp, optical fiber was used for compensation of the unfiltered output. As a result, short pulses down to a picosecond and an RF peak increase by 10 dB could be measured with a standard single-mode fiber (Fig. 6), meaning that the raw pulses at the output of the laser were up-chirped. The shortest pulses were obtained using +10.9 ps/nm external dispersion, yielding pulses of about one picosecond after deconvolution (Fig. 7), but, as seen, secondary pulses are present. This and the substructure seen in the optical spectrum show that not all the lasing modes were locked into one regime of mode-locking. The high value of external dispersion needed questions whether the usual theory of mode-locking underlies the actual mechanism here.
FIG. 3. (Color online) Output power vs input current under uniform injection and as a function of the reverse bias voltage over the saturable absorber (SA) for the 4-mm (a) and 1-mm (b) lasers. The black arrows represent the increase direction of the reverse bias voltage.

FIG. 4. Optical spectra of the 4-mm and 1-mm lasers for an output power of about 8 mW with absorber section reverse biased.

FIG. 5. Pulse width vs filter peak wavelength with eye guide for the 4-mm laser.

FIG. 6. RF spectra for the 4-mm laser without chirp compensation and with optimal chirp compensation.

FIG. 7. Autocorrelation trace of the 4-mm laser output with +10.9 ps/nm dispersion compensation (540 m SMF) and Gaussian fit.
Another explanation would be four-wave mixing combined with the additional non-linearity from the saturable absorber that creates coherence between adjacent modes, which, after dispersion compensation, creates a pulse.

Similarly, such investigation has also been carried out on the 1-mm laser and showed that this one also exhibits strongly chirped pulses. This time, raw pulses were detected with direct autocorrelation measurement, i.e., without any filter or fiber. Their duration is about 18 ps (Fig. 8, inset). The use of 60 m of single-mode fiber increased the RF peak height (Fig. 9), and the pulse duration decreased to 7 ps (Fig. 8), thus showing that the chirp sign is the same as that of the 4-mm laser.

It should be noted that the mode-locking potential of the 4-mm laser has been investigated by the extended Lau’s model. Results showed that, given the laser geometry, mode-locking should indeed happen with the working conditions used to obtain the results reported in this paper. The investigation is still ongoing for the 1-mm laser.

IV. NOISE MEASUREMENTS FOR THE 4-MM LASER

Noise measurements were carried out on the 4-mm laser. Results show a single side-band phase noise of \(-80\) dBc/Hz at 100 kHz offset and an average timing jitter of 800 fs (Fig. 10 and Fig. 11). This is about 15 dB lower than what was previously reported for single quantum well lasers. This performance is mostly attributed to the high inversion and damping induced by the use of quantum dashes and probably enhanced by the use of the double cap method for the growth. Indeed, as mentioned earlier, the latter could allow the growth with fewer defects, which are known to be a source of generation-recombination noise.

V. CONCLUSION

As a conclusion, mode-locking in low-threshold, two-section InAs/InP quantum dash lasers at 41 GHz and 10.6 GHz was demonstrated at 1.59 μm. Mode-locking was suspected from the shape change of the optical spectrum. By using a tuneable filter, pulses could be measured by autocorrelation at several positions in the optical spectrum. These results supported the hypothesis of chirped pulses. By using...
single-mode fiber, picosecond pulses could be measured in the 4-mm laser with a dispersion of +10.9 ps/nm for chirp compensation, meaning that raw pulses are strongly up-chirped. Noise measurement in the 10.6-GHz laser showed that the laser exhibits, at 100 kHz offset, 15 dB less noise than what was previously reported for single quantum well lasers.

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